

HMC466LP4 / 466LP4E

v03.1109



MMIC VCO w/ BUFFER AMPLIFIER, 6.1 - 6.72 GHz

Typical Applications

Low noise MMIC VCO w/Buffer Amplifier for:

- VSAT & Microwave Radio
- CATV & Broadcast Relays
- Test Equipment & Industrial Controls
- Military

Features

Pout: +4.5 dBm

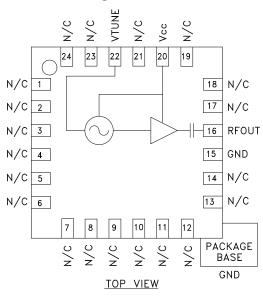
Phase Noise: -101 dBc/Hz @100 KHz

No External Resonator Needed

Single Supply: +3V @ 31 mA

24 Lead 4x4mm QFN Package: 16 mm²

Functional Diagram



General Description

The HMC466LP4 & HMC466LP4E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs with integrated resonators, negative resistance devices, varactor diodes, and buffer amplifiers. Covering 6.1 to 6.72 GHz, the VCO's phase noise performance is excellent over temperature, shock, vibration and process due to the oscillator's monolithic structure. Power output is 4.5 dBm typical from a single supply of 3V @31mA. The voltage controlled oscillator is packaged in a low cost leadless QFN 4 x 4 mm surface mount package.

Electrical Specifications, $T_{\Delta} = +25^{\circ}$ C, Vcc = +3V

Parameter	Min.	Тур.	Max.	Units
Frequency Range	6.1 - 6.72			GHz
Power Output	1.5	4.5		dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RF Output		-101		dBc/Hz
Tune Voltage (Vtune)	0		10	V
Supply Current (Icc) (Vcc = +3V)		31		mA
Tune Port Leakage Current			10	μΑ
Output Return Loss		7		dB
Harmonics 2nd 3rd		-13 -24		dBc dBc
Pulling (into a 2.0:1 VSWR)		11		MHz pp
Pushing @ Vtune= +5V		30		MHz/V
Frequency Drift Rate		0.8		MHz/°C

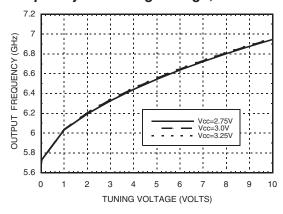


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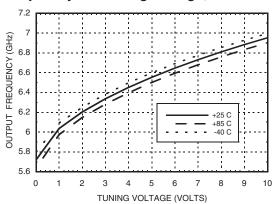


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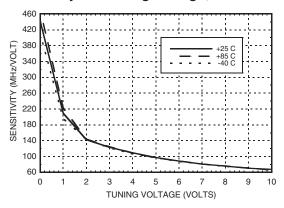
Frequency vs. Tuning Voltage, T= 25°C



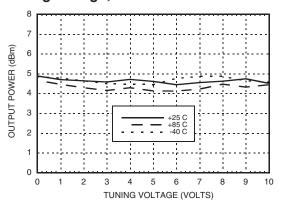
Frequency vs. Tuning Voltage, Vcc= +3V



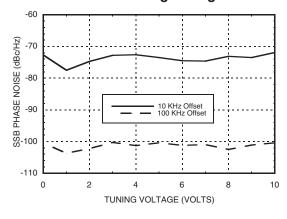
Sensitivity vs. Tuning Voltage, Vcc= +3V



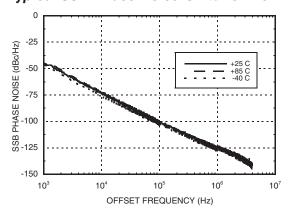
Output Power vs.
Tuning Voltage, Vcc= +3V



Phase Noise vs. Tuning Voltage



Typical SSB Phase Noise @ Vtune= +5V



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Absolute Maximum Ratings

Vcc	+3.5 Vdc	
Vtune	0 to +11V	
Channel Temperature	135 °C	
Continuous Pdiss (T = 85°C) (derate 6.28 mW/°C above 85°C)	5.65 W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	

Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)	
2.75	22	
3.0	31	
3.25	41	

Note: VCO will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
 PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOT FOR SUGGESTED LAND PATTERN.

Package Information

.003[0.08] C

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC466LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H466 XXXX
HMC466LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H466 XXXX

SEATING

PLANE

-C-

- [1] Max peak reflow temperature of 235 $^{\circ}\text{C}$
- [2] Max peak reflow temperature of 260 $^{\circ}\text{C}$
- [3] 4-Digit lot number XXXX